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BIB DATA SHEET

CONFIRMATION NO. 1576

SERIAL NUM	MBER FILING O			1(c) CLASS		GROUP ART UNIT		ATTORNEY DOCKET			
10/553,57	'3	10/17/2			427		1792		NO. Serie 6070		
		RUL	E								
APPLICANTS Christian Dussarrat, Ibaraki, JAPAN; Jean-Marc Girard, Paris, FRANCE; Takako Kimura, Tsukuba, JAPAN; Naoki Tamaoki, Tokyo, JAPAN; Yuusuke Sato, Tokyo, JAPAN; ** CONTINUING DATA ****************************** This application is a 371 of PCT/IB04/01346 04/08/2004 ** FOREIGN APPLICATIONS ************************************											
05/30/2006 Foreign Priority claimed Yes ☐ No 35 USC 119(a-d) conditions met ☑ Yes ☐ No Verified and /ELIZABETH A			Met after Allowance		STATE OR COUNTRY JAPAN	DRAV	SHEETS TOT RAWINGS CLAI		MS CLAIMS		
Acknowledged BURKHART/ Examiner's Signature			Initials		JAI AIN	5		10	1		
ADDRESS AIR LIQUIDE Intellectual Property 2700 POST OAK BOULEVARD, SUITE 1800 HOUSTON, TX 77056 UNITED STATES											
TITLE											
Methods for producing silicon nitride films by vapor-phase growth											
							☐ All Fees				
	FEES: Authority has been given in Paper						☐ 1.16 Fees (Filing)				
1 FII 11903 FFF 1	No to charge/credit DEPOSIT ACCOUNT No for following:						☐ 1.17 Fees (Processing Ext. of time)				
1000							1.18 Fees (Issue)				
							Other				
							☐ Credit				